INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Jun 19 IC24 Data Handbook

1998 Apr 28



Philips Semiconductors

74LVC139

FEATURES

- Wide supply voltage range of 1.2 to 3.6 V
- In accordance with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5 V
- CMOS lower power consumption
- Direct interface with TTL levels
- Demultiplexing capability
- Two independent 2-to-4 decoders
- Multifunction capability
- Active LOW mutually exclusive outputs
- Output drive capability 50 Ω transmission lines at 85°C

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

DESCRIPTION

The 74LVC139 is a low-voltage, low-power, high-performance Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74LVC139 is a dual 2-to-4 line decoder/demultiplexer. This device has two independent decoders, each accepting two binary weighted inputs (nA₀ and nA₁) and providing four mutually exclusive active LOW outputs (n \overline{Y}_0 to n \overline{Y}_3). Each decoder has an active LOW input (nE).

When $n\overline{E}$ is HIGH, every output is forced HIGH. The enable can be used as the data input for a 1-to-4 demultiplexer application.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA to $n\overline{Y}_n$, nE to $n\overline{Y}_n$,	$C_L = 50 \text{ pF};$ $V_{CC} = 3.3 \text{ V}$	3.3 3.2	ns
Cl	Input capacitance		5.0	pF
C _{PD}	Power dissipation capacitance per multiplexer	V _{CC} = 3.3 V Notes 1 and 2	36	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W) P_D = C_{PD} × V_{CC}² × f_i + \sum (C_L × V_{CC}² × f_o) where: f_i = input frequency in MHz; C_L = output load capacity in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V; \sum (C_L × V_{CC}² × f_o) = sum of the outputs.

2. The condition is $V_1 = GND$ to V_{CC}

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic SO	–40°C to +85°C	74LVC139 D	74LVC139 D	SOT109-1
16-Pin Plastic SSOP Type II	–40°C to +85°C	74LVC139 DB	74LVC139 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC139 PW	74LVC139PW DH	SOT403-1

PIN CONFIGURATION

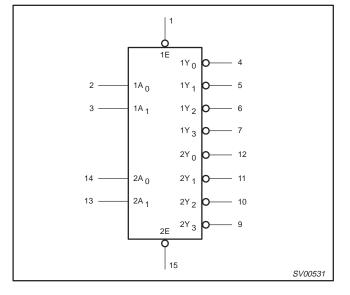
1 \$\vee{Y}_1\$ \$\vee{B}\$ 2\$\vee{Y}_0\$ 1 \$\vee{Y}_2\$ \$\vee{B}\$ 10 2\$\vee{Y}_1\$ 1 \$\vee{Y}_3\$ \$\vee{T}\$ 11 2\$\vee{Y}_2\$ GND \$\vee{B}\$ 12 2\$\vee{Y}_3\$	1Ē 1 1A ₀ 2 1A ₁ 3 1Ÿ0 4	1	6 V _{CC} 5 2E 4 2A ₀ 3 2A ₁	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	1Ÿ ₀ 4			
GND 8 12 273				
				0./00500

PIN DESCRIPTION

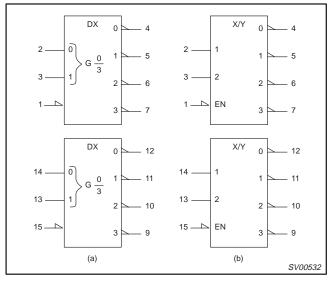
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 15	1Ē, 2Ē	Enable inputs (active LOW)
2, 3	1A ₀ , 1A ₁	Address inputs
14, 13	2A ₀ , 2A ₁	
4, 5, 6, 7	$1\overline{Y}_0$ to $1\overline{Y}_3$	Outputs (active LOW)
12, 11, 10, 9	$2\overline{Y}_0$ to $2\overline{Y}_3$	
8	GND	Ground (0 V)
16	V _{CC}	Positive supply voltage

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LOGIC DIAGRAM



LOGIC SYMBOL (IEEE/IEC)



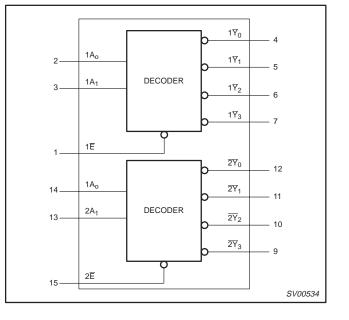
FUNCTION TABLE

INPUTS		OUTPUTS				
nĒ	nA ₀	nA ₁	n₹₀	n <mark></mark> ₹1	n₹2	n₹3
Н	Х	Х	Н	Н	Н	Н
L	L	L	L	Н	Н	Н
L	н	L	н	L	н	н
L	L	н	н	н	L	н
L	н	Н	Н	Н	Н	L

NOTES:

H = HIGH voltage level L = LOW voltage level

X = don't care



FUNCTIONAL DIAGRAM

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Dual 2-to-4 line decoder/demultiplexer

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT		
STWIDOL	FARAMETER	CONDITIONS	MIN	MAX	UNIT	
Vcc	DC supply voltage (for max. speed performance)		2.7	3.6	V	
VCC	DC supply voltage (for low-voltage applications)		1.2	3.6	v	
VI	DC input voltage range		0	5.5	V	
Vo	DC output voltage range		0	V _{CC}	V	
T _{amb}	Operating free-air temperature range in free air		-40	+85	°C	
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V	

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +5.5	V
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	± 50	mA
V _O	DC output voltage	Note 2	-0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	± 50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Power dissipation per package P _{TOT} – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)		above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V)

			L				
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -				
			MIN	TYP ¹	MAX	1	
Maria		V _{CC} = 1.2V	V _{CC}			v	
V _{IH}	HIGH level input voltage	V _{CC} = 2.7 to 3.6V	2.0] `	
V		$V_{CC} = 1.2V$			GND	v	
V _{IL}	LOW level input voltage	V _{CC} = 2.7 to 3.6V			0.8	1 `	
V _{OH}	V _{OH} HIGH level output voltage	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.5				
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V _{CC} -0.2	V _{CC}			
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -12mA$	V _{CC} -0.6			1 `	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -24mA$	V _{CC} -0.8			1	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12mA$			0.40		
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 24mA$			0.55	1	
ł	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V \text{ or GND}$		±0.1	±5	μA	
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V; V_1 = V_{CC} \text{ or GND}; I_0 = 0$		0.1	10	μA	
ΔI_{CC}	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$; $I_{O} = 0$		5	500	μΑ	

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC CHARACTERISTICS

GND = 0 V; t_r = t_f $\leq~$ 2.5 ns; CL = 50 pF; RL = 500 $\Omega;$ T_amb = -40°C to +85°C

			LIMITS					
SYMBOL	PARAMETER	WAVEFORM	V _C	_C = 3.3V ±0.	.3V	V _{CC} =	: 2.7V	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	
t _{PHL} /t _{PLH}	Propagation delay nA_n to \overline{Y}_n	1, 3	1.5	3.3	6.0		7.5	ns
t _{PHL} /t _{PLH}	Propagation delay nĒ to Y _n	2, 3	1.5	3.2	5.5		6.5	ns

NOTE:

1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \geq 2.7$ V V_M = 0.5 \times V_{CC} at V_{CC} < 2.7 V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

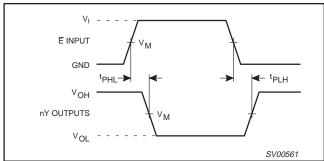


Figure 1. Input (nA) to output (nY) propagation delays.

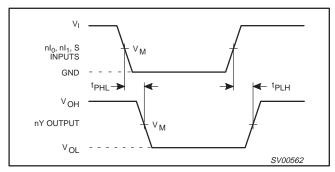


Figure 2. Enable input $(n\overline{E})$ to output $(n\overline{Y}n)$ propagation delays.

TEST CIRCUIT

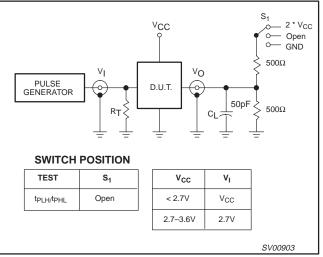
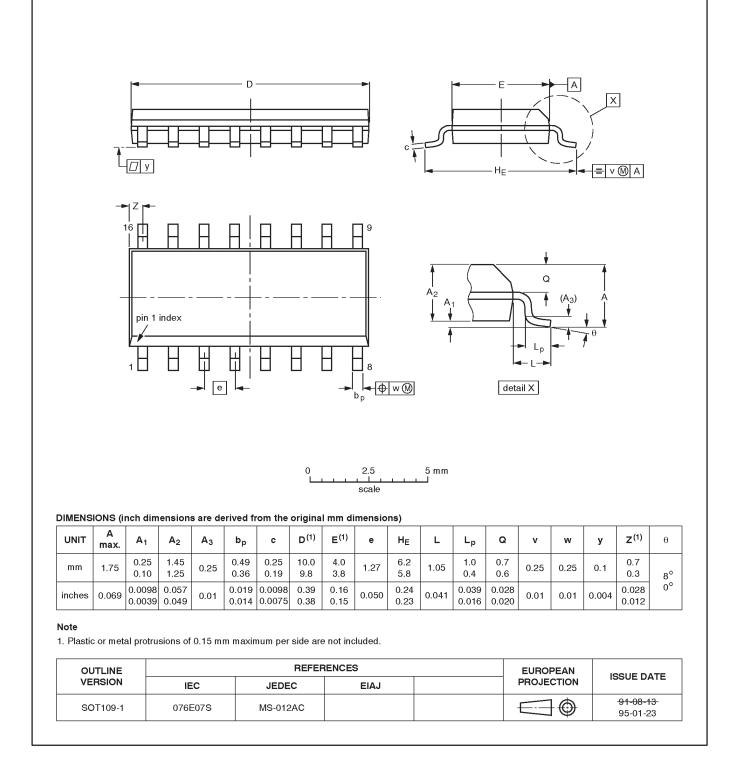


Figure 3. Load circuitry for switching times.

SO16:

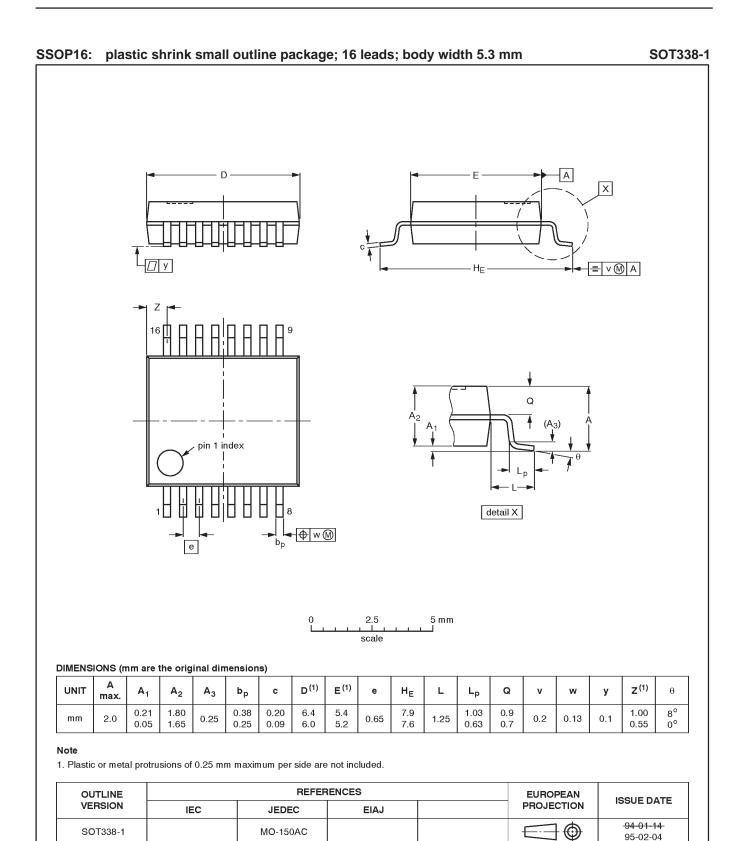
Dual 2-to-4 line decoder/demultiplexer

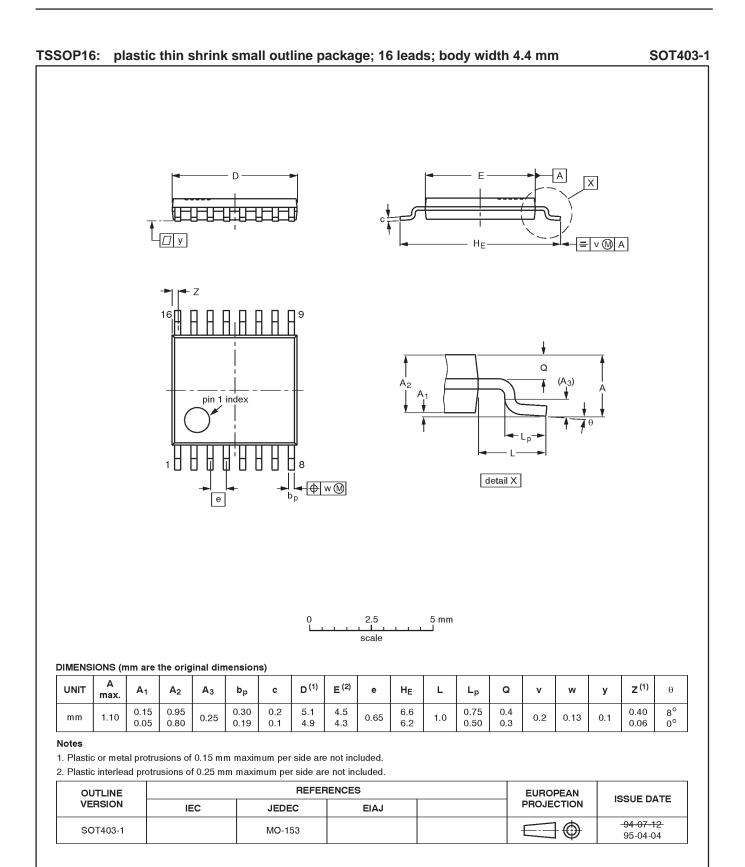
plastic small outline package; 16 leads; body width 3.9 mm



74LVC139

SOT109-1





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DEFINITIONS					
Data Sheet Identification Product Status Definition					
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